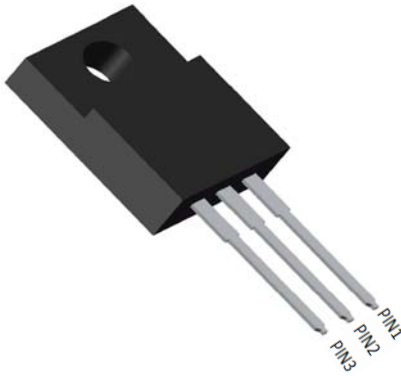


Ultra-Fast Recovery Rectifier Diodes



Features

- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Adopt GPP chip
- Passivation for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** ITO-220AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	SF1640FCT-B1-0000S
Device Marking Code			SF1640FCT
Repetitive Peak Reverse Voltage	VRRM	V	400
Average Rectified Output Current @60Hz half sine-wave, R-load, T _c (FIG.1)	I _o	A	16
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _a =25°C	IFSM	A	100
Current Squared Time @1ms≤t≤8.3ms T _j =25°C	I ² t	A ² s	41
Storage Temperature	T _{stg}	°C	-55 ~ +150
Junction Temperature	T _j	°C	-55 ~ +150

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	SF1640FCT-B1-0000S
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=8.0A	1.5
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	uA	V _{RM} =VRRM T _a =25°C	10
	I _{RRM2}		V _{RM} =VRRM T _a =125°C	500
Reverse Recovery Time	T _{rr}	ns	I _F =0.5A, I _{RM} =1A , I _{RR} =0.25A	35

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	SF1640FCT-B1-0000S
Thermal Resistance Between junction and case	R _{θJ-C}	°C/W	2.5



SF1640FCT-B1-0000S

Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
SF1640FCT-B1-0000S	Approximate 1.47	50	1000	5000	Tube

Characteristics (Typical)

FIG1: I_o - T_c Curve

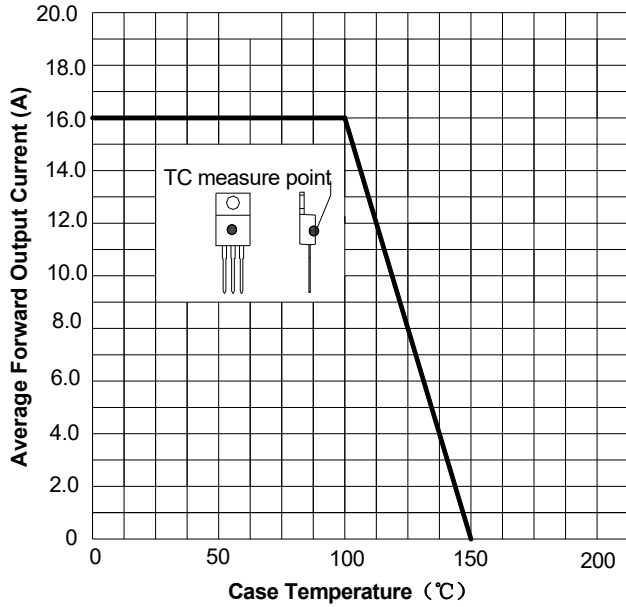


FIG2: Surge Forward Current Capability

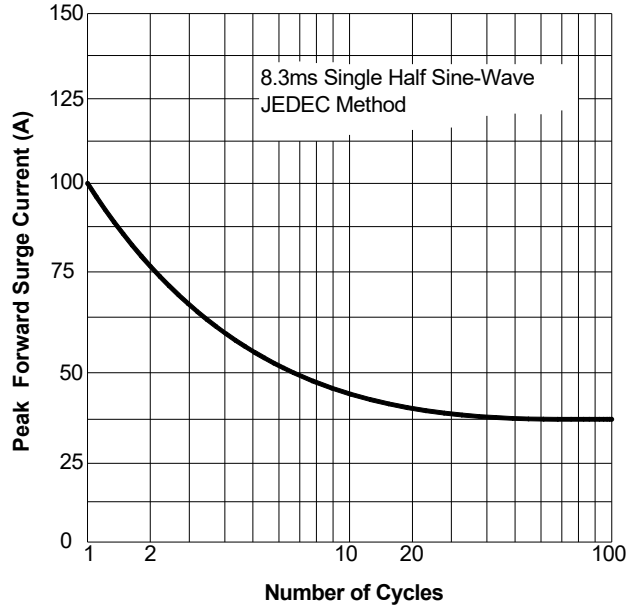


FIG3: Forward Voltage

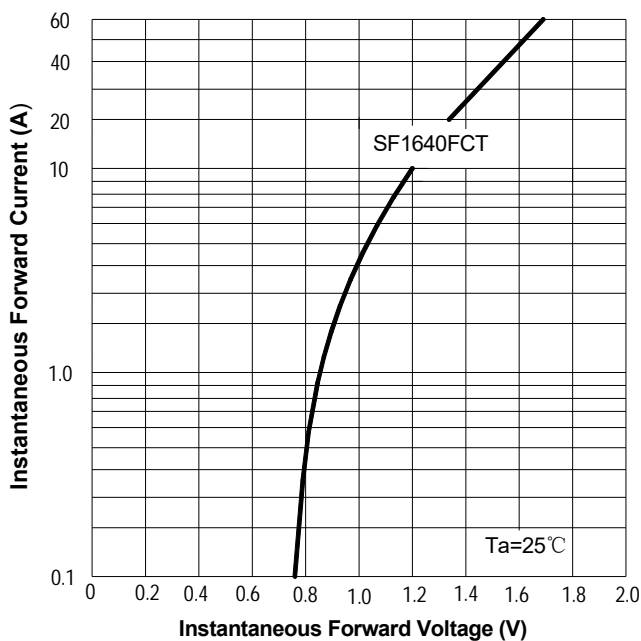


FIG4: Typical Reverse Characteristics

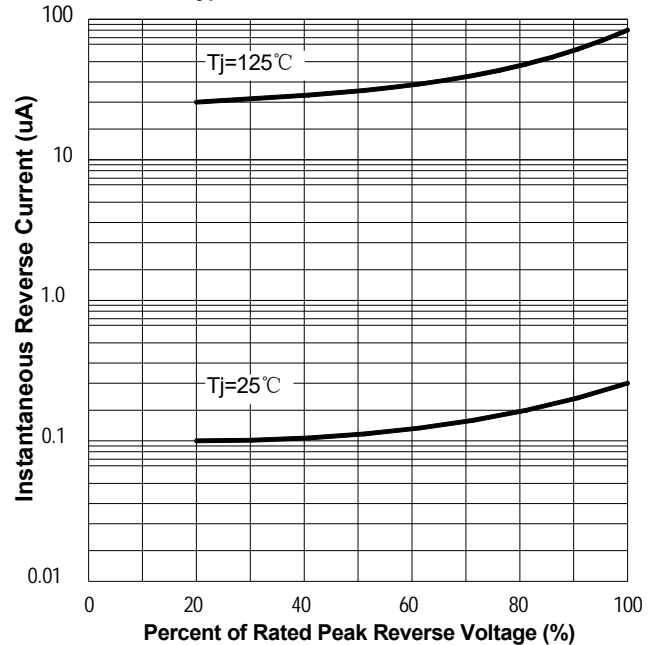
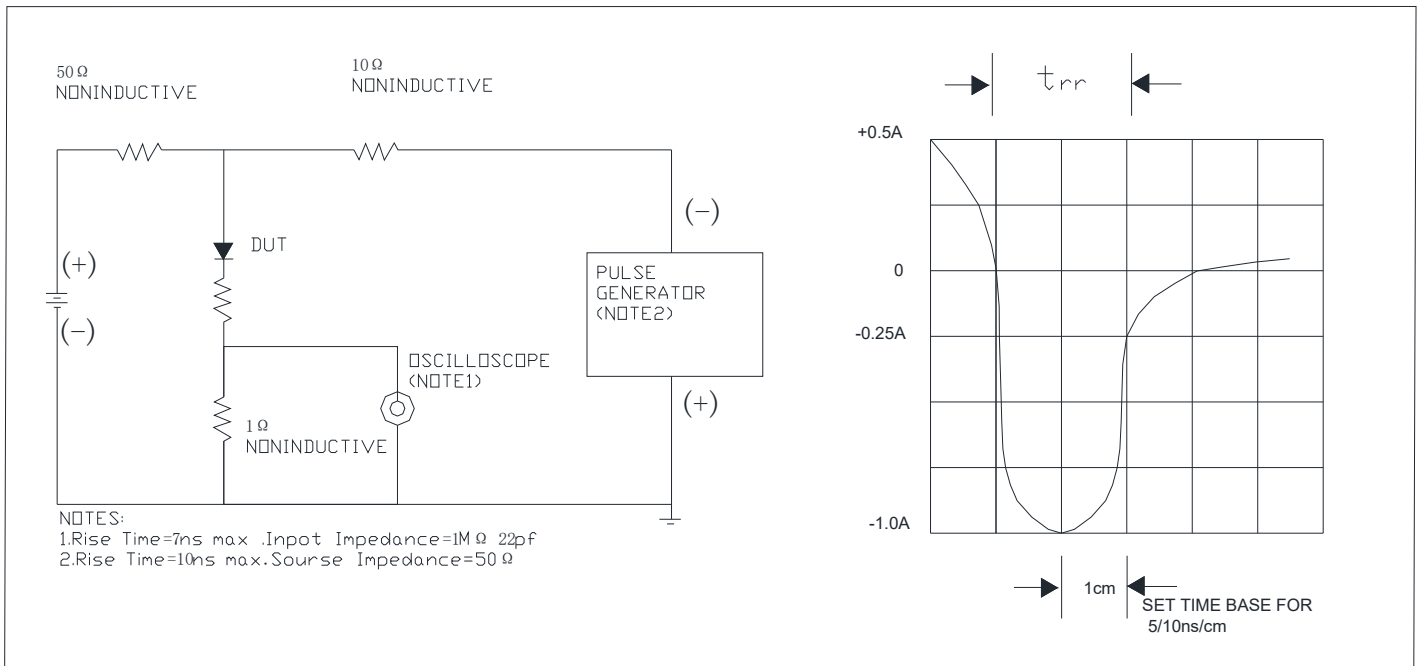
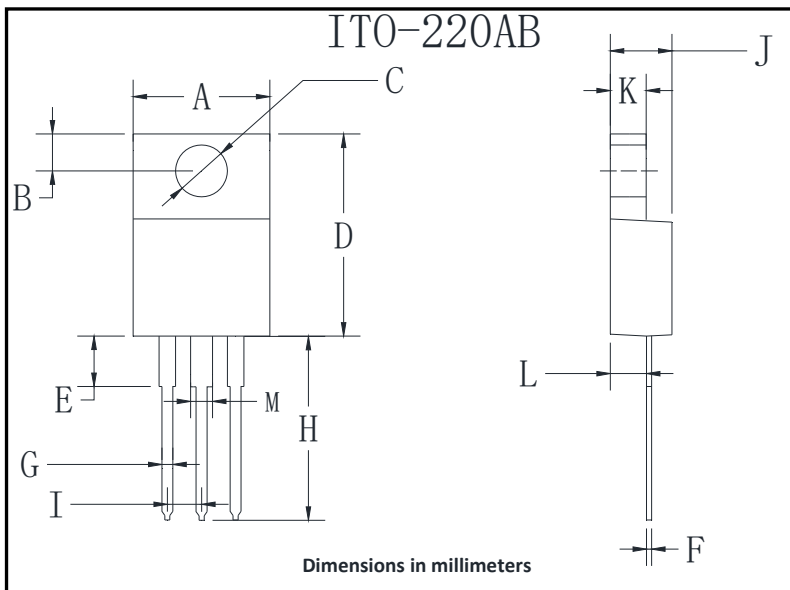


FIG.5 Diagram of circuit and Testing wave form of reverse recovery time



Outline Dimensions



ITO-220AB		
Dim	Min	Max
A	9.7	10.7
B	2.15	3.25
C	2.6	3.8
D	14.4	15.9
E	3.1	4.5
F	0.4	0.8
G	0.4	0.8
H	12.7	14.2
I	1.80	2.95
J	3.9	5.1
K	2.1	3.56
L	2.1	3.2
M	1.4	1.8



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